

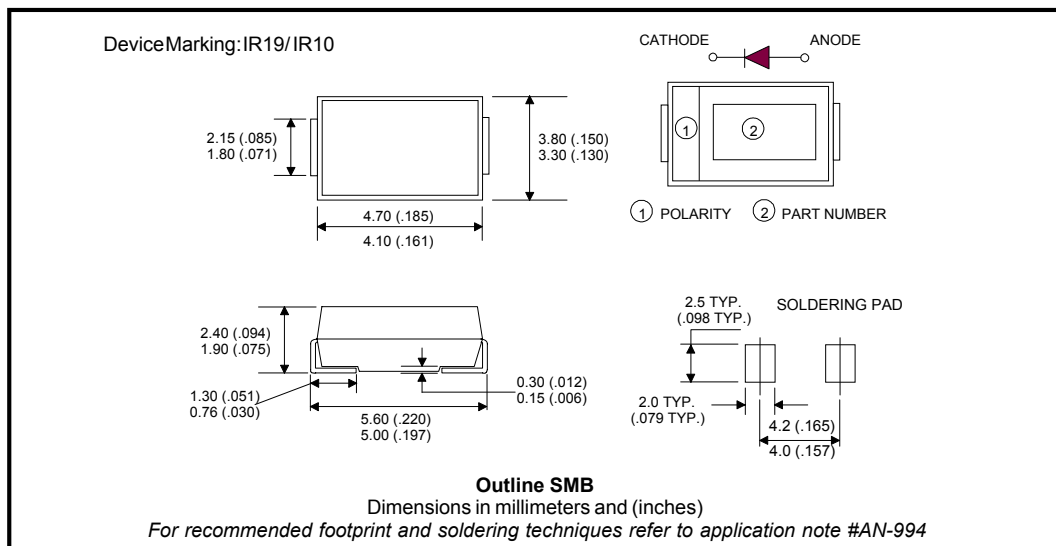
**Major Ratings and Characteristics**

| Characteristics                    | MBR190TR<br>MBR1100TR | Units      |
|------------------------------------|-----------------------|------------|
| $I_{F(AV)}$ Rectangular waveform   | 1.0                   | A          |
| $V_{RRM}$                          | 90 - 100              | V          |
| $I_{FSM}$ @ $t_p = 5 \mu s$ sine   | 870                   | A          |
| $V_F$ @1.0Apk, $T_J = 125^\circ C$ | 0.63                  | V          |
| $T_J$ range                        | -55 to 175            | $^\circ C$ |

**Description/Features**

The MBR190TR, MBR1100TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



### Voltage Ratings

| Part number  | MBRS190TR | MBRS1100TR |
|--|-----------|------------|
| V <sub>R</sub> Max. DC Reverse Voltage (V)             | 90        | 100        |
| V <sub>RWM</sub> Max. Working Peak Reverse Voltage (V) |           |            |

### Absolute Maximum Ratings

| Parameters  | Value | Units | Conditions   |
|---|-------|-------|--|
| I <sub>F(AV)</sub> Max. Average Forward Current                   | 1.0   | A     | 50% duty cycle @ T <sub>L</sub> = 147 °C, rectangular waveform             |
| I <sub>FSM</sub> Max. Peak One Cycle Non-Repetitive Surge Current | 870   | A     | Following any rated load condition and with rated V <sub>RRM</sub> applied |
|   | 50    |       |  |
| E <sub>AS</sub> Non-Repetitive Avalanche Energy                   | 5.0   | mJ    | T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.5A, L = 10mH                   |
| I <sub>AR</sub> Repetitive Avalanche Current                      | 0.2   | A     |  |

### Electrical Specifications

| Parameters   | Value | Units | Conditions   |
|--|-------|-------|--|
| V <sub>FM</sub> Max. Forward Voltage Drop (1)<br>* See Fig. 1    | 0.78  | V     | @ 1A, T <sub>J</sub> = 25 °C   |
|  | 0.62  | V     | @ 1A, T <sub>J</sub> = 125 °C  |
| I <sub>RM</sub> Max. Reverse Leakage Current (1)<br>* See Fig. 2 | 0.5   | mA    | T <sub>J</sub> = 25 °C   |
|  | 1.0   | mA    | T <sub>J</sub> = 125 °C  |
| C <sub>T</sub> Typical Junction Capacitance                      | 42    | pF    | V <sub>R</sub> = 5V <sub>DC</sub> , (test signal range 100kHz to 1MHz) 25 °C |
| L <sub>S</sub> Typical Series Inductance                         | 2.0   | nH    | Measured lead to lead 5mm from package body                                  |
| dv/dt Max. Volatge Rate of Charge<br>(Rated V <sub>R</sub> )     | 10000 | V/ µs |  |

(1) Pulse Width < 300µs, Duty Cycle < 2%

### Thermal-Mechanical Specifications

| Parameters  | Value       | Units  | Conditions                |
|---|-------------|--------|---------------------------|
| T <sub>J</sub> Max. Junction Temperature Range (*)              | -55 to 175  | °C     |                           |
| T <sub>stg</sub> Max. Storage Temperature Range                 | -55 to 175  | °C     |                           |
| R <sub>thJL</sub> Max. Thermal Resistance Junction to Lead (**) | 36          | °C/W   | DC operation (See Fig. 4) |
| R <sub>thJA</sub> Max. Thermal Resistance Junction to Ambient   | 80          | °C/W   | DC operation              |
| wt Approximate Weight   | 0.10(0.003) | g(oz.) |                           |
| Case Style  | SMB         |        | Similar to DO-214AA       |
| Device Marking  | IR19-IR10   |        |                           |

(\*)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

(\*\*) Mounted 1 inch square PCB

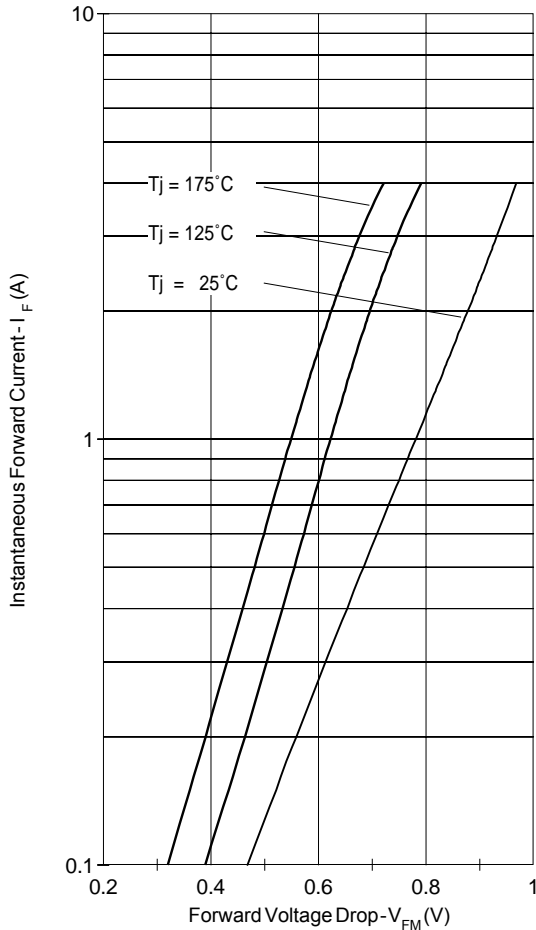


Fig. 1 - Maximum Forward Voltage Drop Characteristics

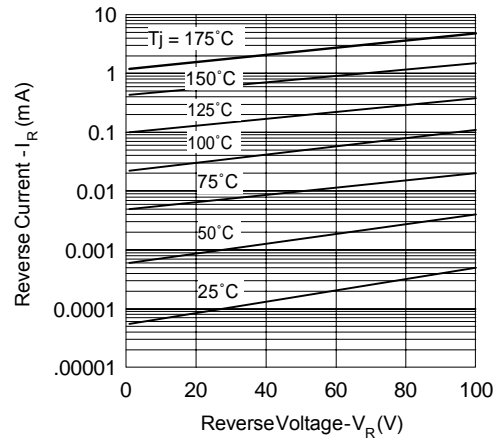


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

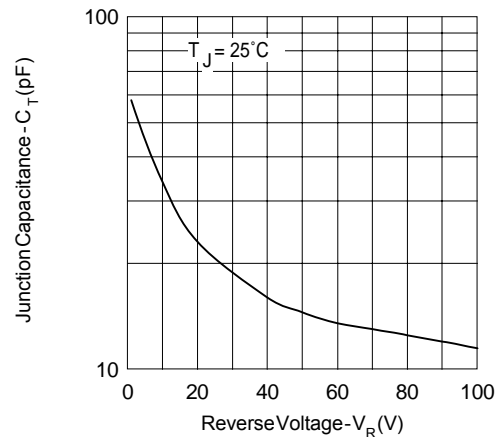


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

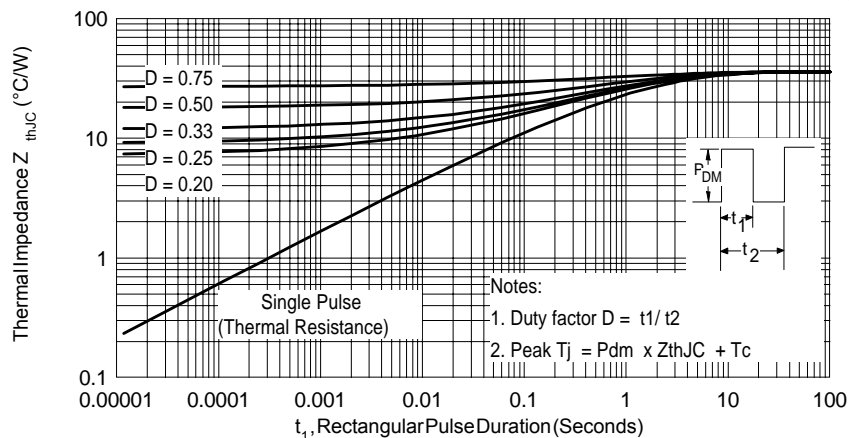


Fig. 4 - Max. Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)

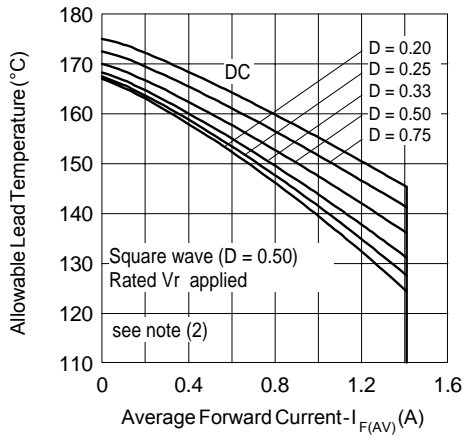


Fig. 4- Maximum Average Forward Current Vs. Allowable Lead Temperature

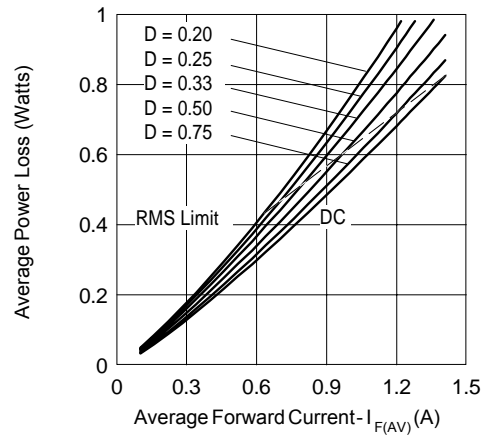


Fig. 5- Maximum Average Forward Dissipation Vs. Average Forward Current

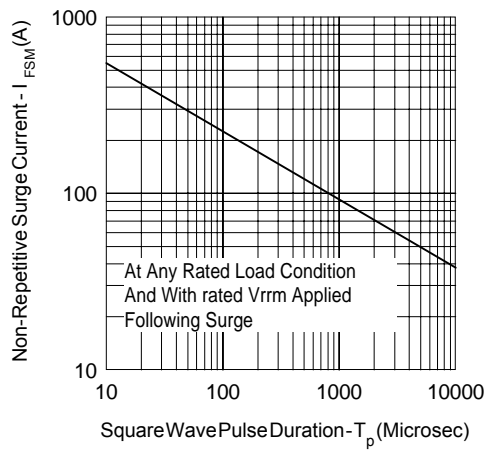


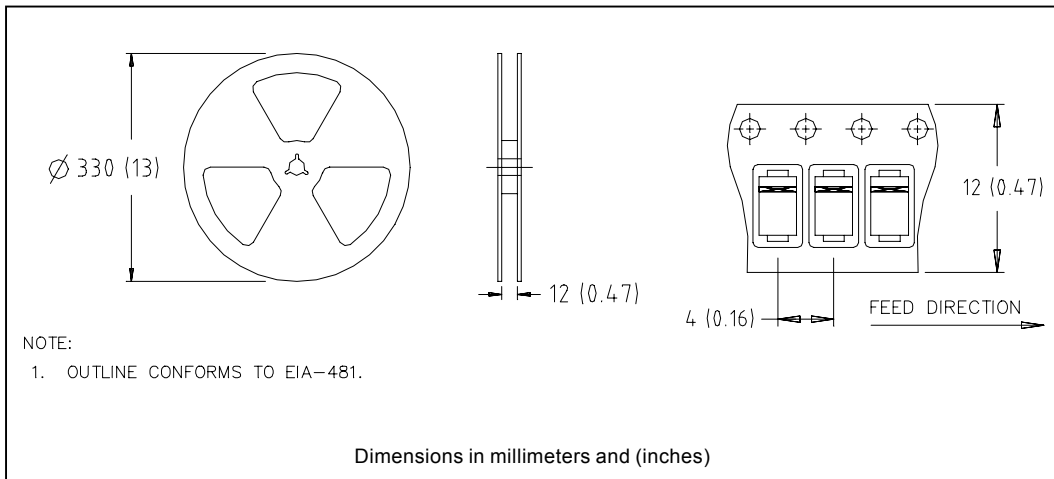
Fig. 6- Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used:  $T_c = T_j - (Pd + Pd_{REV}) \times R_{thJC}$ ;

$Pd$  = Forward Power Loss =  $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$  (see Fig. 6);

$Pd_{REV}$  = Inverse Power Loss =  $V_{R1} \times I_{R1} (1 - D)$ ;  $I_{R1} @ V_{R1} = 80\%$  rated  $V_R$

**Tape & Reel Information**



**Marking & Identification**

**Ordering Information**

|   |   |
|---|---|
| <p>Each device has marking and identification on two rows.</p> <ul style="list-style-type: none"> <li>- The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", then Current and Voltage.</li> <li>- The second row shows the data code: Year and Week.</li> </ul> <p>See below marking diagram.</p> <p><b>FIRST ROW</b><br/>             IR 10</p> <p><b>SECOND ROW</b><br/>             Date Code<br/>             YY WW</p> | <p><b>MBRS1100TR - TAPE AND REEL</b></p> <p>WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY ( IN MULTIPLES OF 3000 PIECES).</p> <p>EXAMPLE: MBRS1100TR - 6000 PIECES</p> |
|---|---|

Data and specifications subject to change without notice.  
This product has been designed and qualified for Industrial Level.  
Qualification Standards can be found on IR's Web site.

International  
**IOR** Rectifier

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